

being formed between said first electrode and said second electrode.

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cont
2. (Amended) The liquid-crystal display device according to claim 1, wherein said second electrode comprises an extended part of said transparent electrode.
 3. (Amended) The liquid-crystal display device according to claim 1, wherein said first electrode is connected to said address wirings by the same transparent conductive film as used for said transparent electrode.
 4. (Amended) The liquid-crystal display device according to claim 1, wherein said first electrode is connected to said address wirings by the same conductive film as in said data wirings.
 5. (Amended) The liquid-crystal display device according to claim 1, wherein a part of said capacitor section is superimposed through said gate insulating film on said address wirings.
 6. (Amended) The liquid-crystal display device according to claim 1, wherein a width of said address wirings is constant in said picture element area and wherein said capacitor section is entirely superimposed through said gate insulating film on said address wirings.
 7. (Amended) The liquid-crystal display device according to claim 1, wherein said thin-film transistor section and said data wirings are covered with one of said upper layer insulating film and said transparent conductive film.
 8. (Amended) The liquid-crystal display device according to claim 1, wherein one of said upper layer insulating film has a thickness which is less than a thickness of said gate insulating film, and a dielectric constant of said upper layer insulating film is greater than a dielectric constant of said gate insulating film.

9. (Amended) The liquid-crystal display device according to claim 1, wherein said upper layer insulating film comprises a complex film comprising a plurality of insulating films.

10. (Amended) The liquid-crystal display device according to claim 1, wherein said upper layer insulating film comprises at least one of a silicon nitride film, silicon oxide film and metal oxide film.

11. (Amended) The liquid-crystal display device according to claim 1, wherein an auxiliary capacitive common wiring is formed in parallel with said address wirings and wherein said capacitor section is one of partially and totally superimposed on said auxiliary capacitive common wiring.

12. (Amended) The liquid-crystal display device according to claim 11, wherein at least two connections are made between said first electrode and said address wirings or between said first electrode and said auxiliary capacitive common wiring.

13. (Amended) The liquid-crystal display device according to claim 1, wherein said capacitor section is formed by connecting, in parallel, a first capacitive component comprising a part of said address wirings, said first electrode and said gate insulating film being located between said address wirings and said first electrode with a second capacitive component comprising said first electrode, said second electrode and said upper layer insulating film being located between said first electrode and said second electrode.

14. (Amended) A method for producing the liquid-crystal display device of claim 1, comprising:

- forming a plurality of address wirings on an insulating substrate;
- forming a gate insulating film on said address wirings;
- forming a plurality of data wiring on said gate insulating film, so that said data wirings and said address wirings cross each other;
- forming a thin-film transistor for selectively connecting said data wirings with said

transparent electrode disposed in each picture element area by a gate connected to said address wirings, in each picture element area surrounded by said address wirings and data wirings;

forming a first electrode using the same conductive film as used to form said data wirings;

forming an upper layer insulating film on said first electrode;

forming a second electrode using the same transparent conductive film as used to form said transparent electrode; and

forming said capacitor section using said first electrode, said second electrode, and said upper layer insulating film.

15. (Amended) The method for producing the liquid-crystal display device according to claim 1, wherein said second electrode comprises an extended part of said transparent electrode in said capacitor section.

16. (Amended) The method for producing the liquid-crystal display device according to claim 14, wherein said first electrode is connected to said address wirings by the same transparent conductive film as in said transparent electrode.

17. (Amended) The method for producing the liquid-crystal display device according to claim 14, wherein said first electrode is connected to said address wirings by the same conductive film as in said data wirings.

37 18. (Amended) A method for producing the liquid-crystal display device of claim 11, comprising:

forming a plurality of address wirings on an insulating substrate;

forming a plurality of auxiliary capacitive common wiring parallel with said address wirings;

forming a gate insulating film on said auxiliary capacitive common wiring;

forming a plurality of data wirings on said gate insulating film, so that said address

wirings and data wirings cross each other;

forming a thin-film transistor for selectively connecting said data wirings with said transparent electrode in each picture element area by a gate connected to said address wirings, in each picture element area surrounded by said address wirings and data wirings;

forming said first electrode using the same conductive film as used to form said data wirings;

forming said upper insulating film on said first electrode;

forming said second electrode using the same transparent conductive film as used to form said transparent electrode; and

forming said capacitor section using said first electrode, said second electrode and said upper layer insulating film so that said capacitor is one of partially and totally superimposed on said auxiliary capacitive common wiring.

19. (Amended) The method for producing a liquid-crystal display device of claim 14, wherein said first electrode is connected to said transparent electrode and said second electrode is connected to said address wirings and wherein said capacitor section is mounted so that it is superimposed on a part of said address wirings.

20. (Amended) A method for producing the liquid-crystal display device of claim 4, comprising:

forming a plurality of address wirings on an insulating substrate;

forming a gate insulating film on said address wirings;

forming, in said gate insulating film, a through hole which extends to said address wirings;

forming a plurality of data wirings on said gate insulating film so that said address wirings and data wirings cross each other;

forming a thin-film transistor for selectively connecting said data wirings with said transparent electrode in each picture element area by a gate connected to said address wirings, in each picture element area surrounded by said address wirings and data wirings;

forming said first electrode using the same conductive film used to form said data

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wirings;

connecting said first electrode to said address wirings via said through hole formed in said gate insulating film;

forming said upper layer insulating film on said first electrode;

forming said second electrode using the same transparent conductive film used to form said transparent electrode; and

forming said capacitor section using said first electrode, said second electrode and said upper layer insulating film.

21. The liquid-crystal display device of claim 13, wherein said first electrode is connected to said transparent electrode and said second electrode is connected to said address wirings and wherein said capacitor section is mounted so that it is superimposed on a part of said address wirings.

Please add the following new claim:

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-- 22. A method of fabricating a liquid-crystal display device, said method comprising:

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forming a plurality of address wirings on an insulating substrate;

forming a gate insulating film on said address wirings;

forming a plurality of data wirings on said gate insulating film, so that said data wirings and said address wirings cross each other;

forming a thin-film transistor for selectively connecting said data wirings with a transparent electrode by a gate connected to said address wirings, said transparent electrode being located in a picture element area surrounded by said address wirings and data wirings;

forming a first electrode using the same conductive film as used to form said data wirings;

forming an upper layer insulating film on said first electrode;

forming a second electrode using the same transparent conductive film as used to form said transparent electrode; and

forming a capacitor section using said first electrode, said second electrode, and said upper layer insulating film. --
